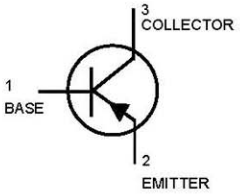
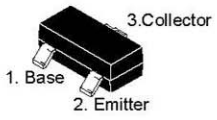
2SA1036K

PNP Silicon





CASE 318–08, STYLE 6
SOT– 23 (TO–236AB)

- **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	– 40	Vdc
Collector–Base Voltage	V_{CBO}	– 40	Vdc
Emitter–Base Voltage	V_{EBO}	– 5.0	Vdc
Collector Current — Continuous	I_C	– 500	mAdc

- **THERMAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR –5 Board (1) T_A=25 °C	P_D	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	°C/W
Alumina Substrate (2) T_A = 25°C	$_D$	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T_J, T_{stg}	–55 to +150	°C

- **ELECTRICAL CHARACTERISTICS** (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Breakdown Voltage (3) (I_C = –1.0 mAdc, I_B = 0)	$V_{(BR)CEO}$	– 40	—	Vdc
Collector–Base Breakdown Voltage (I_C = –0.1mAdc, I_E = 0)	$V_{(BR)CBO}$	– 40	—	Vdc
Emitter–Base Breakdown Voltage (I_E = –0.1mAdc, I_C = 0)	$V_{(BR)EBO}$	– 5.0	—	Vdc
Base Cutoff Current (V_{CE} = –35 Vdc, V_{EB} = –0.4 Vdc)	I_{BEV}	—	– 0.1	µAdc
Collector Cutoff Current (V_{CE} = –35 Vdc, V_{EB} = –0.4 Vdc)	I_{CEX}	—	– 0.1	µAdc

1. FR–5 = 1.0 x 0.75 x 0.062 in.
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.
3. Pulse Test: Pulse Width ≤300 µs; Duty Cycle ≤2.0%.

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● **ELECTRICAL CHARACTERISTICS** (T_A = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain	h_{FE}			—
(I_C = –0.1 mAdc, V_{CE} = –1.0 Vdc)		30	—	
(I_C = –1.0 mAdc, V_{CE} = –1.0 Vdc)		60	—	
(I_C = –10 mAdc, V_{CE} = –1.0 Vdc)		100	—	
(I_C = –150 mAdc, V_{CE} = –2.0 Vdc)(3)		180	390	
(I_C = –500 mAdc, V_{CE} = –2.0 Vdc)(3)		20	—	
Collector–Emitter Saturation Voltage(3)	$V_{CE(sat)}$			Vdc
(I_C = –150mAdc, I_B = –15 mAdc)		—	– 0.4	
(I_C = –500 mAdc, I_B = –50 mAdc)		—	– 0.75	
Base–Emitter Saturation Voltage (3)	$V_{BE(sat)}$			Vdc
(I_C = –150 mAdc, I_B = –15 mAdc)		– 0.75	– 0.95	
(I_C = –500 mAdc, I_B = –50 mAdc)		—	– 1.3	

● **SMALL–SIGNAL CHARACTERISTICS**

Current–Gain — Bandwidth Product	f_T		MHz
(I_C = –20mAdc, V_{CE}= –10 Vdc, f = 100 MHz)	200	—	
Collector–Base Capacitance	C_{cb}		pF
(V_{CB}= –10 Vdc, I_E = 0, f = 1.0 MHz)	—	8.5	
Emitter–Base Capacitance	C_{eb}		pF
(V_{BE} = –0.5 Vdc, I_C = 0, f = 1.0 MHz)	—	30	
Input Impedance	h_{ie}		kΩ
(V_{CE}= –10 Vdc, I_C = –1.0 mAdc, f = 1.0 kHz)	1.5	15	
Voltage Feedback Ratio	h_{re}		X 10^{-4}
(V_{CE}= –10 Vdc, I_C = –1.0 mAdc, f = 1.0 kHz)	0.1	8.0	
Small–Signal Current Gain	h_{fe}		—
(V_{CE}= –10 Vdc, I_C = –1.0 mAdc, f = 1.0 kHz)	60	500	
Output Admittance	h_{oe}		μmhos
(V_{CE}= –10 Vdc, I_C = –1.0 mAdc, f = 1.0 kHz)	1.0	100	

● **SWITCHING CHARACTERISTICS**

Delay Time	(V_{CC} = – 30 Vdc, V_{EB} = –2.0 Vdc,	t_d	—	15	
Rise Time	I_C = –150mAdc, I_{B1} = –15 mAdc)	t_d	—	20	ns
Storage Time	(V_{CC} = –30 Vdc, I_C = –150 mAdc,	t_s	—	225	ns
Fall Time	I_{B1} = I_{B2} = –15 mAdc)	t_f	—	30	

3. Pulse Test: Pulse Width ≤300 μs; Duty Cycle ≤2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

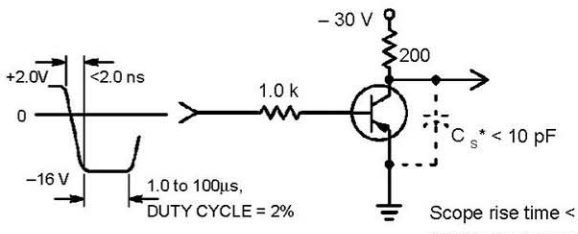

Figure 1. Turn–On Time

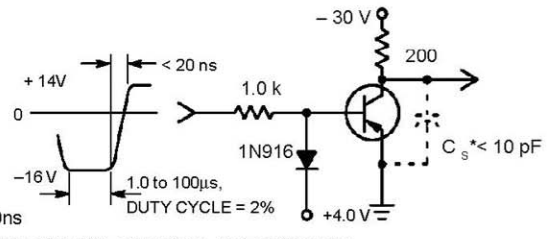

Figure 2. Turn–Off Time

Scope rise time < 4.0ns

*Total shunt capacitance of test jig connectors, and oscilloscope

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TYPICAL TRANSIENT CHARACTERISTICS

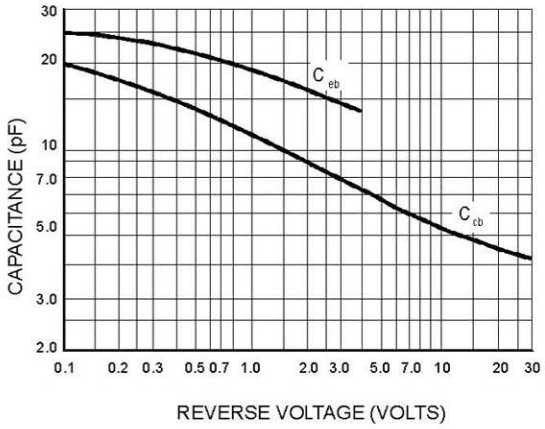

Figure 3. Capacitance

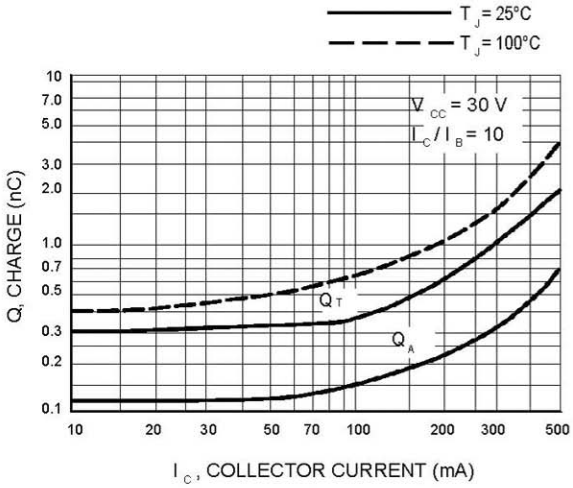

Figure 4. Charge Data

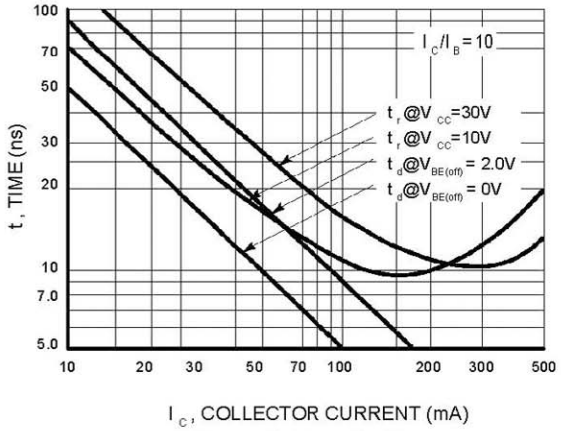

Figure 5. Turn–On Time

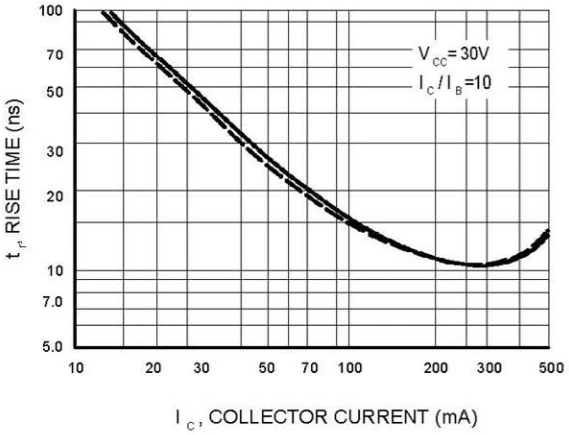

Figure 6. Rise Time

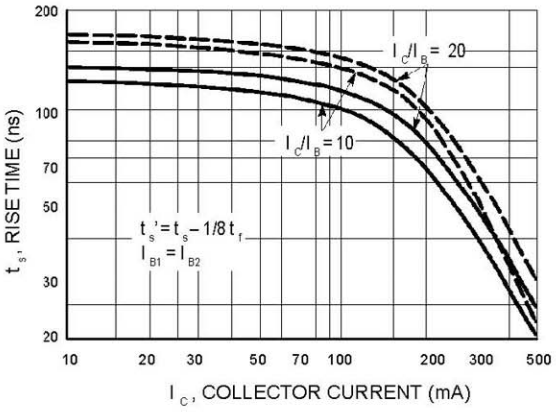

Figure 7. Storage Time

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SMALL–SIGNAL CHARACTERISTICS

NOISE FIGURE

V_{CE} = –10 Vdc, T_A = 25°C

Bandwidth = 1.0 Hz

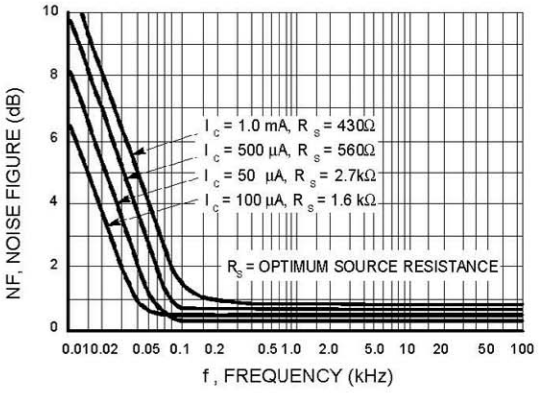

Figure 8. Frequency Effects

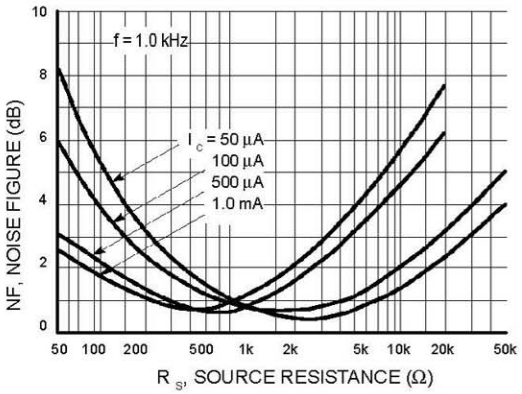

Figure 9. Source Resistance Effects

h PARAMETERS

(V_{CE} = –10 Vdc, f = 1.0 kHz, T_A = 25°C)

This group of graphs illustrates the relationship between h fe and other "h" parameters for this series of ransistors. To obtain these curves, a high–gain and a low–gain unit were selected from the MMBT4401LT1 lines, and the same units were used to develop the correspondingly numbered curves on each graph.

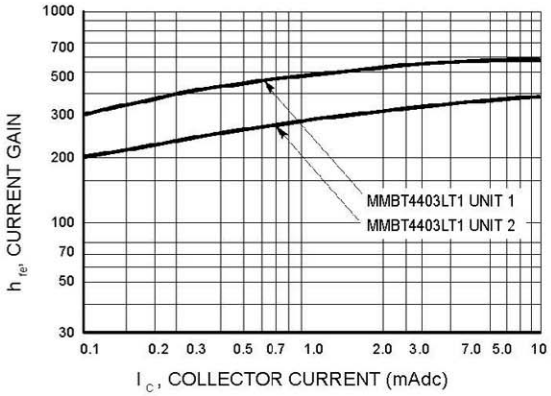

Figure 10. Current Gain

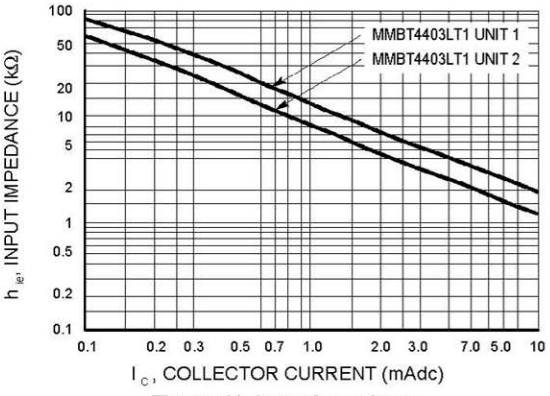

Figure 11. Input Impedance

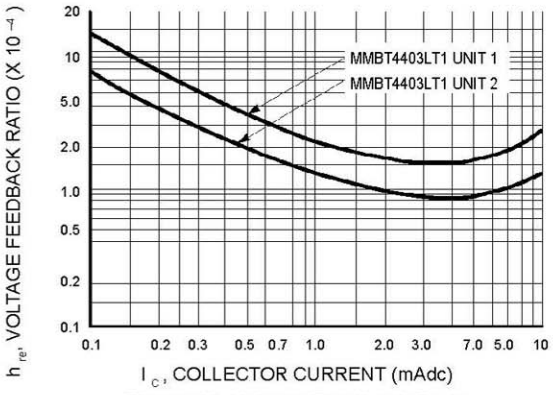

Figure 12. Voltage Feedback Ratio

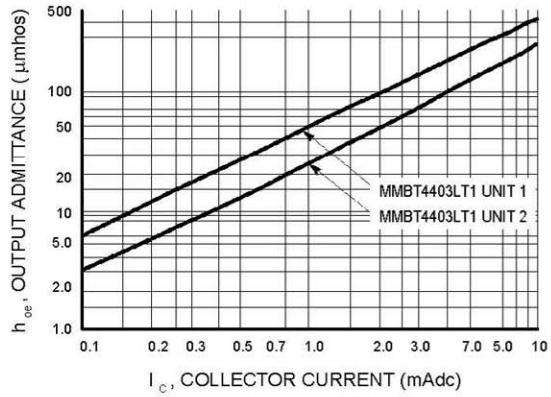

Figure 13. Output Admittance

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STATIC CHARACTERISTICS

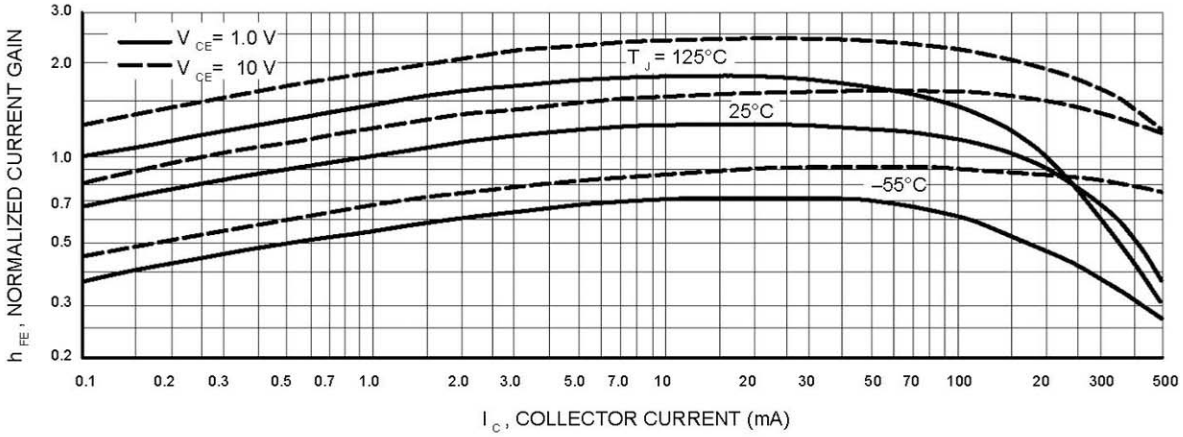

Figure 14. DC Current Gain

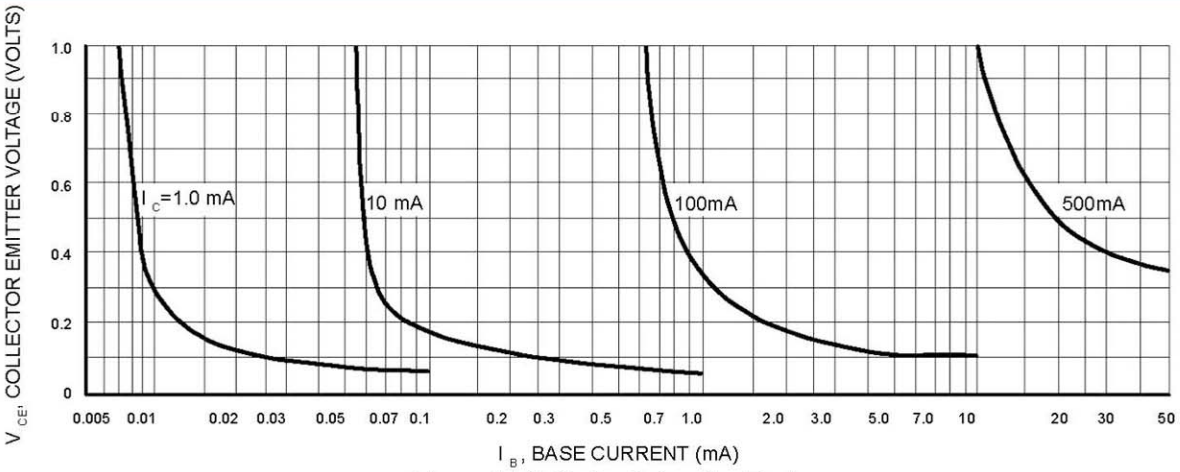

Figure 15. Collector Saturation Region

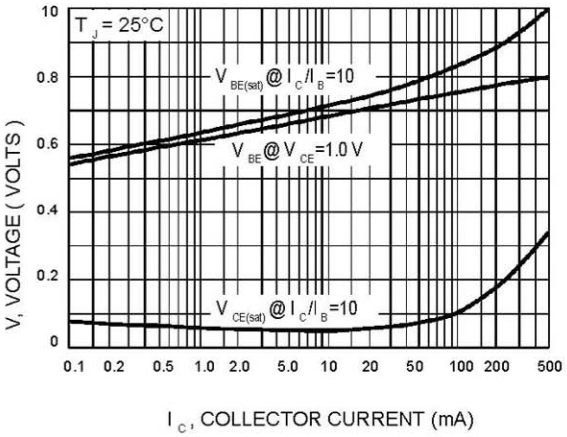

Figure 16. "On" Voltages

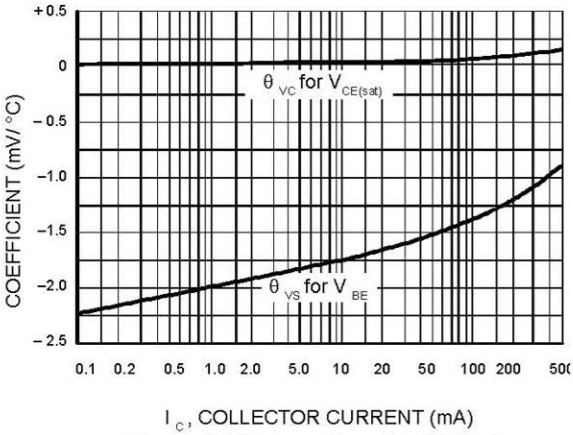

Figure 17. Temperature Coefficients

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